Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Glass
Overall Length:
Terminal Length:
1.000 inches
Overall Diameter:
0.124 inches
Function For Which Designed:
Voltage variable capacitor
Joint Electronic Device Engineering Council/jedec/case Outline Designation:
Do-14
Mounting Method:
Terminal
Features Provided:
Hermetically sealed case and burn in
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
37.0 breakdown voltage, dc
Current Rating Per Characteristic:
3.00 microamperes forward current, average peak
Capacitance Rating In Picofarads:
100.0
Test Data Document:
28815-68-108294 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing,
etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
2 uninsulated wire lead

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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